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system with two memories RAM ROM MRAM

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Patents 1 - 10 on system with two memories RAM ROM MRAM. (0.05 seconds)

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Any status

[Issued patents](#)[Applications](#)Did you mean: **system with two memories RAM ROM DRAM****Bus arbitration in a dual-bus architecture where one bus has relatively high ...**

US Pat. 5363748 - Filed Aug 23, 1991 - Nexgen Microsystems

When it is set, the **MRAM** is active. Bit 1 is the **ROM** Page Select bit; It selects between **two** Optionally, the **MRAM** may be configured as a 64K- by-2 **RAM** in ...**Shared volatile and non-volatile memory**

US Pat. 6894918 - Filed Oct 30, 2003 - Hewlett-Packard Development Company, L.P.

Presently, most random access memory (**RAM**) is sensed through the word lines and the ... Read only memory (**ROM**), for example, is **MRAM** memory cells offer the ...**Method and system for providing redundancy for signaling link modules in a ...**

US Pat. 6778491 - Filed Mar 31, 2000 - Alcatel

Memory 114 can be **RAM**, **ROM**, **CD-ROM**, registers, and/or any other type of ... Signaling Card 140 also includes a Message Dual Port **RAM (MRAM)** 192 and a ...**[APPLICATION] Semiconductor memory device, operational processing device and storage system**

US Pat. 11546950 - Filed Oct 13, 2006 - Renesas Technology Corp.

[0012] Reference 2 likewise intends to achieve a simple memory **system** allowing fast access by using the **FeRAM** or **MRAM** for the **ROM** and **RAM**. ...**Memory cell sensing system and method**

US Pat. 6804145 - Filed Nov 1, 2002 - Hewlett-Packard Development Company, L.P.

It should be noted that other types of **RAM** (for example, **SRAM** and **DRAM**) do not require the signal noise and interference minimization required by **MRAM**. ...**Bridge-type magnetic random access memory (MRAM) latch**

US Pat. 6714441 - Filed Sep 17, 2002 - Micron Technology, Inc.

A common form of memory is random access memory (**RAM**). ... **GMR MRAM** devices separate at least **two** ferromagnetic layers with a metallic layer. ...**System and method for determining the logic state of a memory cell in a ...**

US Pat. 6650562 - Filed Jan 23, 2002 - Hewlett-Packard Development Company, L.P.

3, the **system** and method of the present invention utilizes at least **two** ... to use a non-volatile **MRAM** rather than a volatile **RAM** in certain applications. ...**Crossing transfers for maximizing the effective bandwidth in a dual-bus ...**

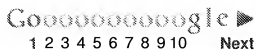
US Pat. 5414820 - Filed Mar 21, 1994 - NexGen, Inc.

When it is set, the **MRAM** is active. Bit 1 is the **ROM** Page Select bit; It selects between **two** 64-KB "pages" for the BIOS **ROM**. Bit 2 is the Spin- Lock bit. ...**System and method for sensing memory cells of an array of memory cells**

US Pat. 6765834 - Filed Nov 19, 2002 - Hewlett-Packard Development Company, L.P.

The **system** and method should be adaptable for used with arrays of **MRAM** ... The memory can include read only memory (**ROM**) or random access 15 memory (**RAM**). ...**Magnetoresistive random access memory (MRAM) cell patterning**

US Pat. 6677165 - Filed Mar 20, 2003 - Micron Technology, Inc.



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